July 2014



# FCH130N60 N-Channel SuperFET<sup>®</sup> II MOSFET 600 V, 28 A, 130 mΩ

## Features

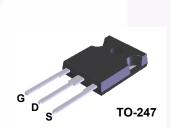
- 650 V @ T<sub>J</sub> = 150°C
- Typ. R<sub>DS(on)</sub> = 112 mΩ
- Ultra Low Gate Charge (Typ. Q<sub>g</sub> = 54 nC)
- Low Effective Output Capacitance (Typ. C<sub>oss(eff.)</sub> = 240 pF)
- 100% Avalanche Tested
- RoHS Compliant

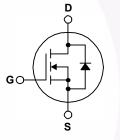
### Applications

- Telecom / Sever Power Supplies
- Industrial Power Supplies
- AC-DC Power Supply

## Description

SuperFET<sup>®</sup> II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This advanced technology is tailored to minimize conduction loss, provide superior switching performance, and withstand extreme dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is suitable for various AC/DC power conversion for system miniaturization and higher efficiency.





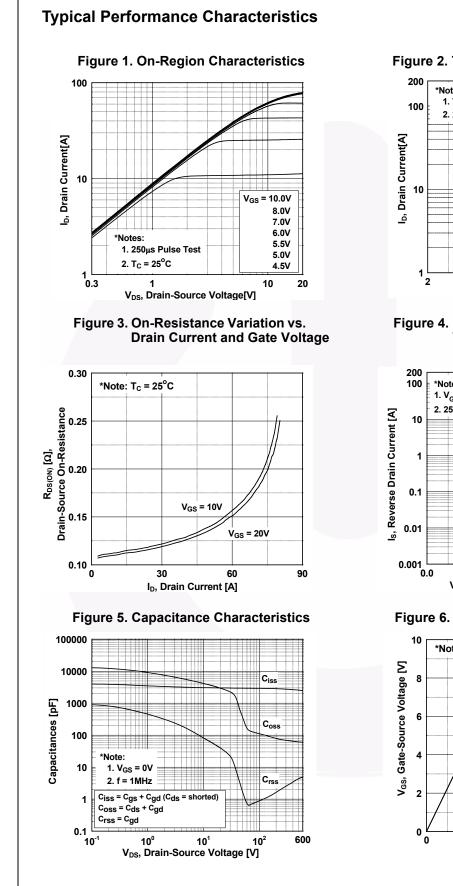
Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

Symbol	Parameter			FCH130N60	Unit
V <sub>DSS</sub>	Drain to Source Voltage			600	V
V <sub>GSS</sub>	Gate to Source Voltage	- DC		±20	V
		- AC	(f > 1 Hz)	±30	- V
ID	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		28	A
		- Continuous (T <sub>C</sub> = 100 <sup>o</sup> C)		18	
I <sub>DM</sub>	Drain Current	- Pulsed	(Note 1)	84	А
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)		720	mJ	
I <sub>AR</sub>	Avalanche Current (Note 1)		6	Α	
E <sub>AR</sub>	Repetitive Avalanche Energy (Note 1)		2.78	mJ	
dv/dt	MOSFET dv/dt			100	V/ns
	Peak Diode Recovery dv/dt (Note 3)		20		
P <sub>D</sub>	Power Dissipation	(T <sub>C</sub> = 25 <sup>o</sup> C)		278	W
		- Derate Above 25°C		2.2	W/ºC
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300	°C

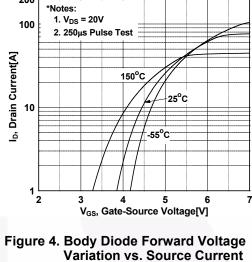
### **Thermal Characteristics**

Symbol	Parameter	FCH130N60	Unit
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	0.45	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient, Max.	40	°C/w

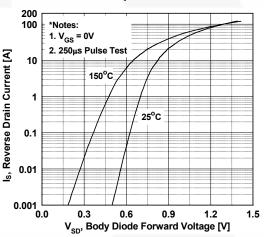
Mir 600 C 650 - - C - - 2.5 - -	) - ) - 0.67 - 2.5 -	30 max. - - - 1 ±100 3.5 130	units Unit Unit V/°C μA nA V
600 C 650 - - - °C - -	) - ) - 0.67 - 2.5 - ; -	- - 1 ±100	- V V/°C - μΑ nA
600 C 650 - - - °C - -	) - ) - 0.67 - 2.5 - ; -	- - 1 ±100	- V V/°C - μΑ nA
C 650	-           0.67           -           2.5           -           5           -           112	- - 1 ±100	V/ºC μA nA
C 650	-           0.67           -           2.5           -           5           -           112	- - 1 ±100	V/ºC μA nA
- - - - -	0.67 - 2.5 - 5 -	- ±100	V/ºC μA nA
- °C - -	- 2.5 -	- ±100	– μA nA
•C -	2.5 - 5 - 112	- ±100	nA
-	- 5 - 112	±100	nA
	5 - 112	3.5	
2.5	112		V
-	112		V
-		130	
-	26		mΩ
		-	S
-	2700	3590	pF
-	65	85	pF
-	2.85	-	pF
-	240	-	pF
-	54	70	nC
-	12	-	nC
4) _	14	-	nC
-	1	-	Ω
_	25	60	n
-	16	42	ns
-	65	140	ns
		-	ns
= 4)		10	113
-	-		A
-	-	-	A
-		1.2	V
-			ns
-	7.0	-	μC
		   - 376	28 84 1.2 - 376 -

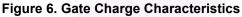


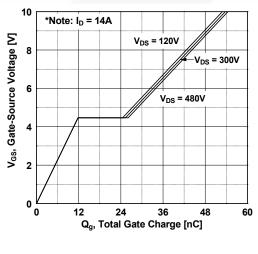




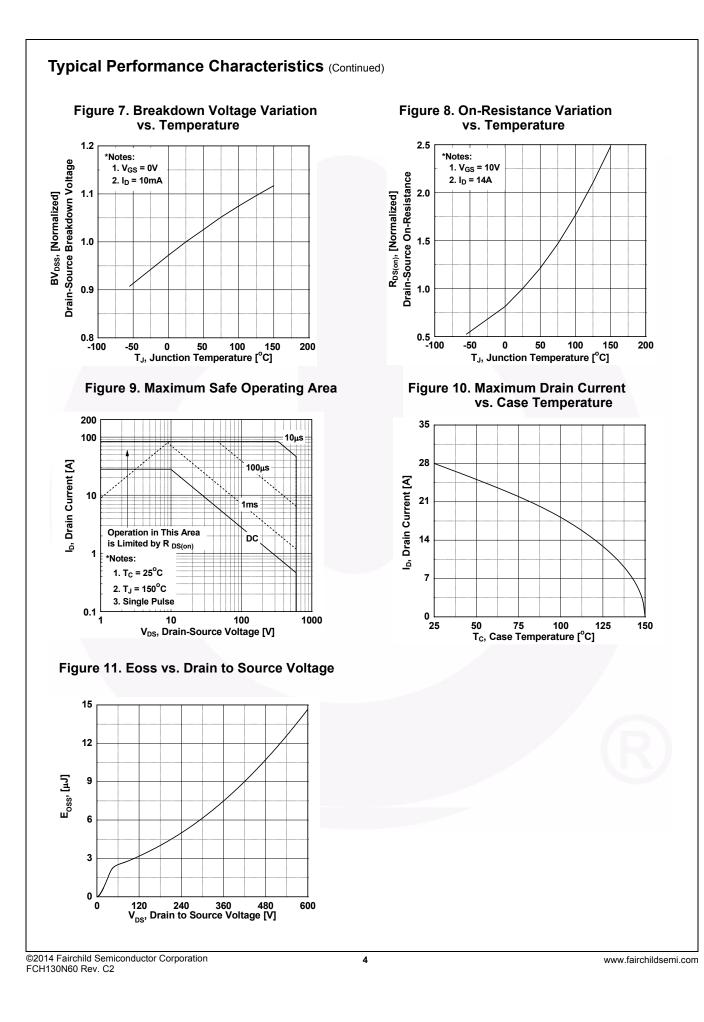
and Temperature

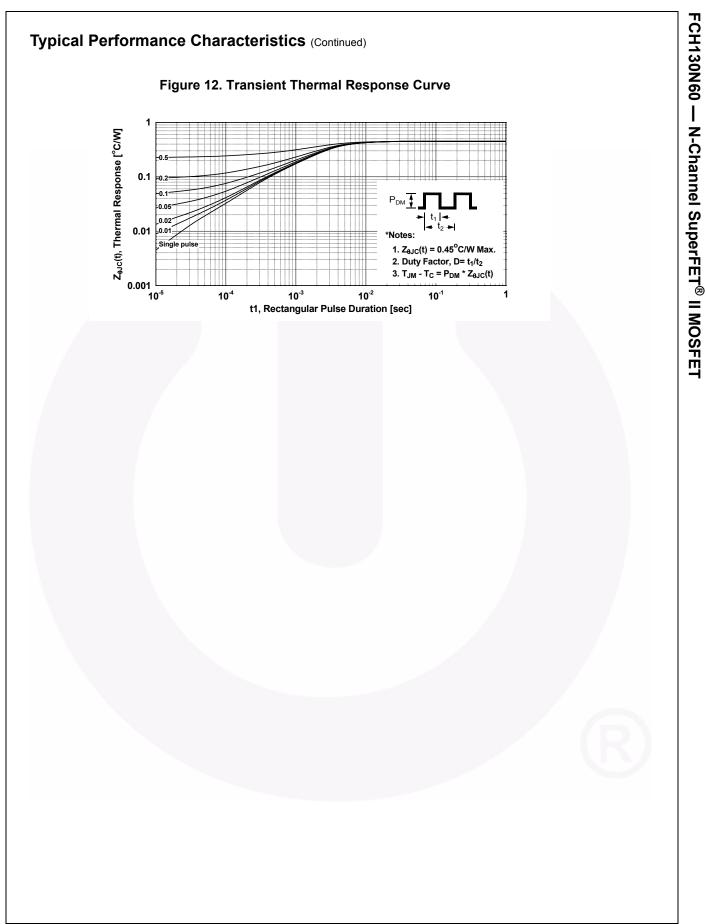


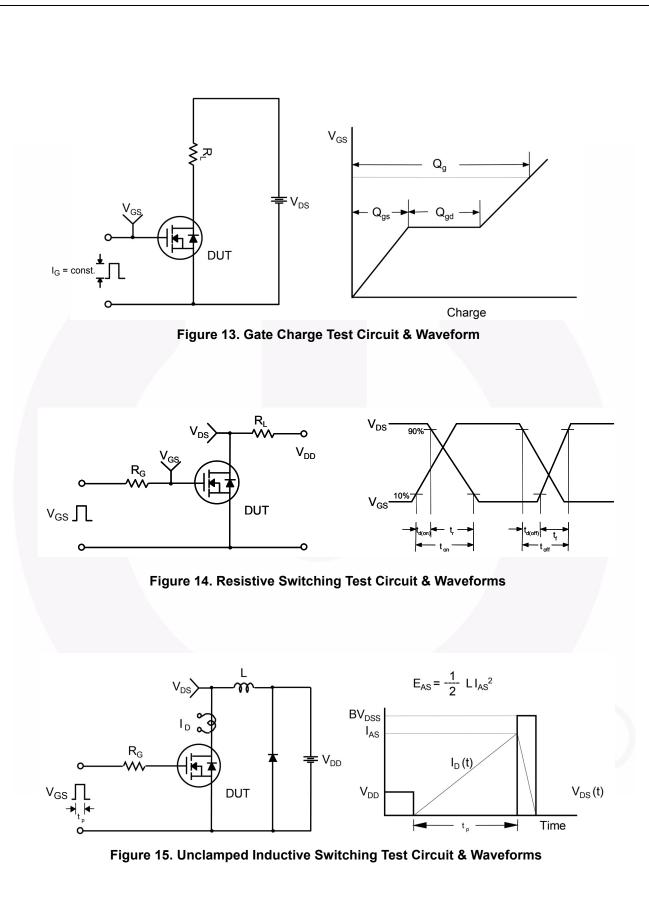




FCH130N60 — N-Channel SuperFET<sup>®</sup> II MOSFET

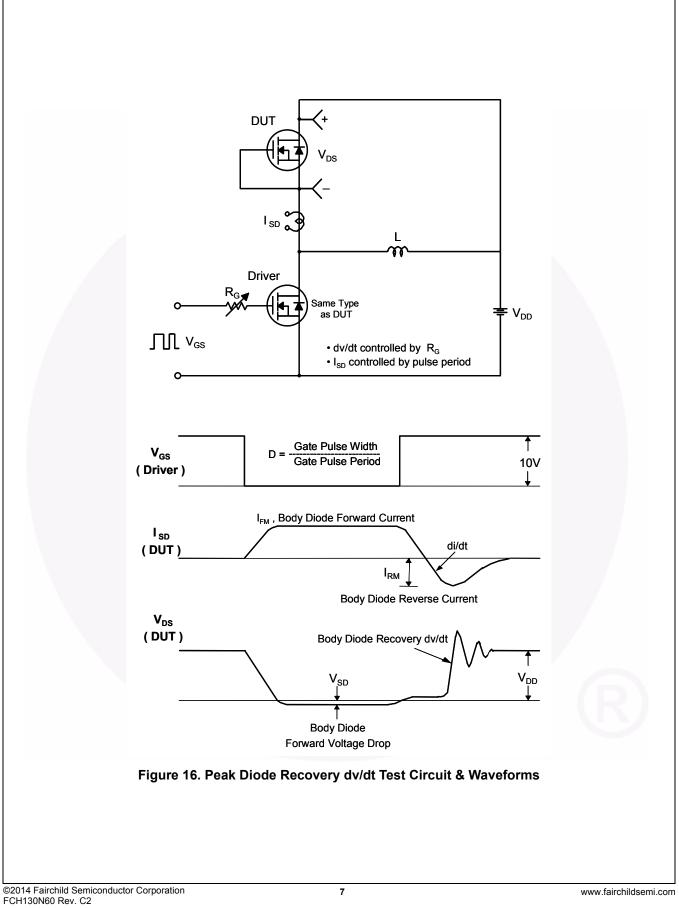


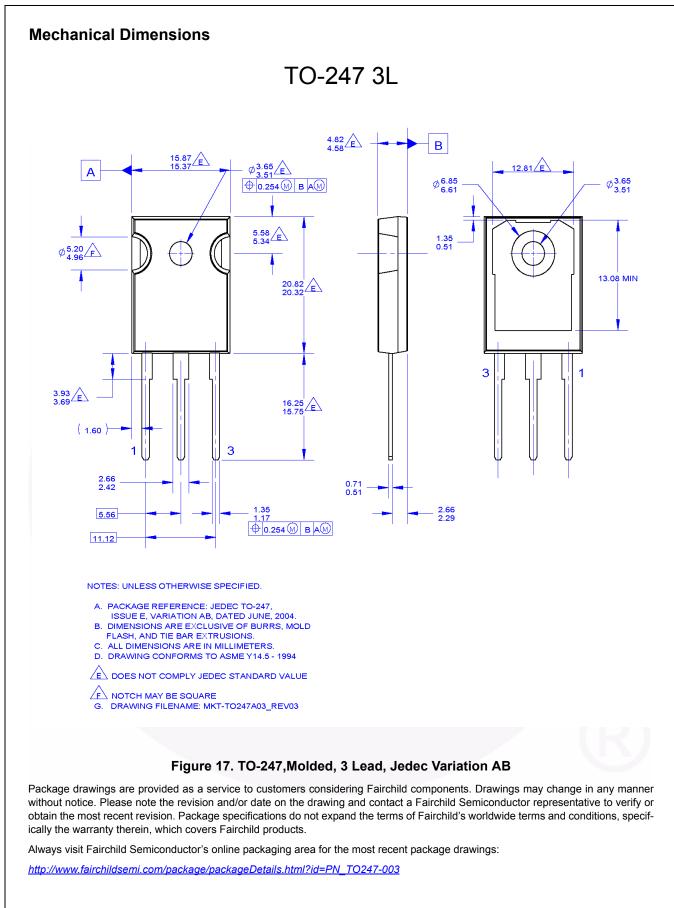




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